

Features

- Formerly FullTec brand
- Extremely high speed performance
- Blocks high voltages and currents
- Very high bandwidth; GHz compatible
- Small package, minimal PCB area
- Simple, superior circuit protection
- RoHS compliant*, UL Recognized SN*

TBU[®] C650 and C850 Protectors

Transient Blocking Units - TBU® Devices

Agency Approval

UL recognized component File # E315805.

Industry Standards

	Model		
Telcordia	GR-1089	Port Type 1, 3, 5	C650 C850
	GR-974	C650 C850	
ITU-T	K.20, K.20E,	C850	

Bourns® C650 and C850 series products are high speed bidirectional protection components, constructed using

MOSFET semiconductor technology, designed to protect against faults caused by short circuits, AC power cross, induction and lightning surges.

The TBU® high speed protector, triggering as a function of the MOSFET, blocks surges and provides an effective barrier behind which sensitive electronics are not exposed to large voltages or currents during surge events. The TBU® device is provided in a surface mount DFN package and meets industry standard requirements such as RoHS and Pb Free solder reflow profiles.

Absolute Maximum Ratings (T_{amb} = 25 °C)

Symbol	Parameter	Value	Unit
V _{imp}	Maximum protection voltage for impulse faults with rise time $\ge 1 \ \mu$ sec	650 850	V
V _{rms}	Maximum protection voltage for continuous V _{rms} faults	300 425	v
Т _{ор}	Operating temperature range	-40 to +85	°C
T _{stg}	Storage temperature range	-65 to +150	°C

Electrical Characteristics (T_{amb} = 25 °C)

Symbol	Parameter		Min.	Тур.	Max.	Unit
I _{op}	Maximum current through the device that will not cause current blocking	Cx50-100-WH Cx50-180-WH Cx50-260-WH			100 180 260	mA
I _{trigger}	Typical current for the device to go from normal operating state to protected state	Cx50-100-WH Cx50-180-WH Cx50-260-WH		150 220 330		mA
l _{out}	Maximum current through the device	Cx50-100-WH Cx50-180-WH Cx50-260-WH			200 360 520	mA
R _{device}	Series resistance of the TBU [®] device	C650-100-WH C650-180-WH C650-260-WH C850-100-WH C850-180-WH C850-260-WH		12 8 8 17 11 11	14.5 10 10 19 14 14	Ω
t _{block}	Maximum time for the device to go from normal operating state to protected state			1	μs	
I _{quiescent}	Current through the triggered TBU [®] device with 50 Vdc circl voltage		1		mA	
V _{reset}	Voltage below which the triggered TBU® device will transition normal operating state		14		v	

C650 and C850 TBU® protectors are bidirectional; specifications are valid in both directions.

*RoHS Directive 2002/95/EC Jan 27, 2003 including Annex. Specifications are subject to change without notice. Customers should verify actual device performance in their specific applications.

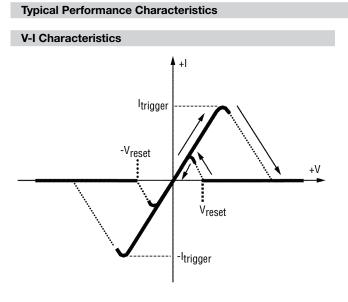


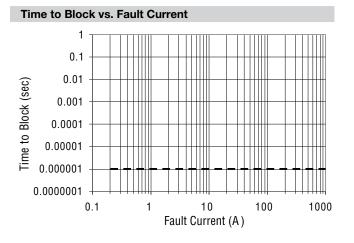
Applications

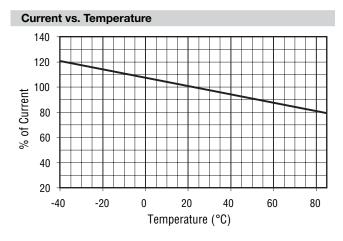
- Combo voice / xDSL linecards
- Voice linecards
- MDF, primary protection modules
- Process control equipment
- Test and measurement equipment
- General electronics

TBU® C650 and C850 Protectors

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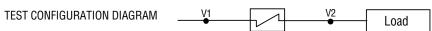




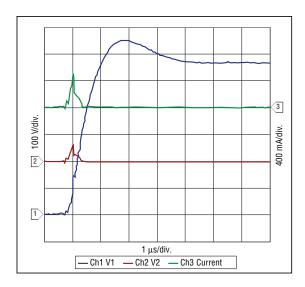
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Operational Characteristics

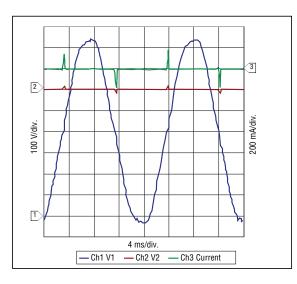
The graphs below demonstrate the operational characteristics of the TBU[®] protector. For each graph the fault voltage, protected side voltage, and current is presented.



C650 Lightning, 650 V



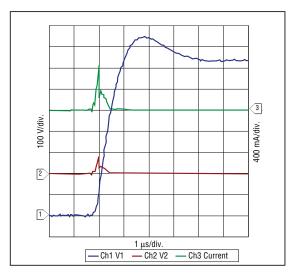
C650 Power Fault, 300 Vrms, 100 A



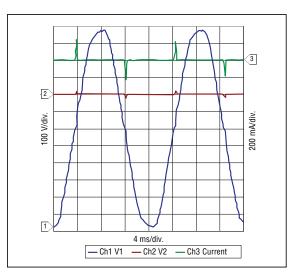
Specifications are subject to change without notice. Customers should verify actual device performance in their specific applications.

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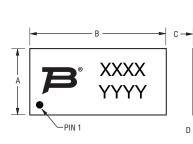
C850 Lightning, 850 V

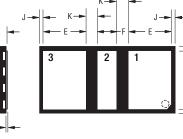


C850 Power Fault, 425 Vrms, 100 A



Product Dimensions





Pad Designation

NC = Solder to PCB; do not make electrical connection, do not connect to ground.

TOP VIEW

1.15

(.045)

Recommended Pad Layout

 $\frac{0.70}{(.028)}$

2.625

(.103)

 $\frac{3.55}{(.140)}$

BOTTOM VIEW

Pad #

1

2

3

SIDE VIEW

3.90 4.00 4.10 А (.154)(.157) (.161) 8.15 8.25 8.35 В (.325)(.321)(.329) 0.80 0.85 0.90 С (.031)(.033) (.035)0.000 0.025 0.050 D (.000)(.001)(.002)2.55 2.65 2.60 Е (.100) (.102) (.104) 1.10 1.15 1.20 F (.043)(.045)(.047)3.55 3.45 3.50 Н (.136) (.138) (.140)0.20 0.25 0.30 J (.012) (.008)(.010)0.65 0.70 0.75 Κ (.026) (.028) (.030)0.20 0.25 0.30 Ν (.008)(.010)(.012)

DIMENSIONS: $\frac{MM}{(INCHES)}$

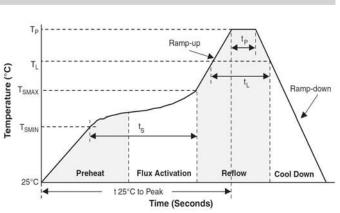
TBU[®] protectors have matte-tin termination finish. Suggested layout should use non-solder mask define (NSMD). Recommended stencil thickness is 0.10-0.12 mm (.004-.005 in.) with stencil opening size 0.025 mm (.0010 in.) less than the device pad size. As when heat sinking any power device, it is recommended that, wherever possible, extra PCB copper area is allowed. For minimum parasitic capacitance, do not allow any signal, ground or power signals beneath any of the pads of the device.

Thermal Resistances

Symbol	Parameter	Value	Unit
Rth(j-a)	Junction to leads (package)	116	°C/W

Reflow Profile

Profile Feature	Pb-Free Assembly
Average Ramp-Up Rate (Tsmax to Tp)	3 °C/sec. max.
Preheat - Temperature Min. (Tsmin) - Temperature Max. (Tsmax) - Time (tsmin to tsmax)	150 °C 200 °C 60-180 sec.
Time maintained above: - Temperature (TL) - Time (tL)	217 °C 60-150 sec.
Peak/Classification Temperature (Tp)	260 °C
Time within 5 °C of Actual Peak Temp. (tp)	20-40 sec.
Ramp-Down Rate	6 °C/sec. max.
Time 25 °C to Peak Temperature	8 min. max.



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Тур.

Max.

Min.

Dim.

N٦

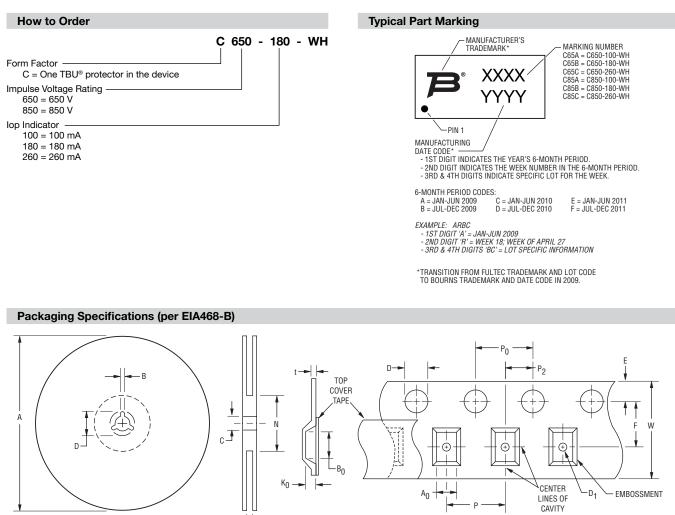
Apply

In/Out

NC

In/Out

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USER DIRECTION OF FEED
QUANTITY: 3000 PIECES PER REEL

Device		4	В		С		D		G	N
Device	Min.	Max.	Min.	Max.	Min.	Max.	Min.	in. Max. Ref. I	Ref.	
C650, C850	326 (12.835)	330.25 (13.002)	<u>1.5</u> (.059)	<u>2.5</u> (.098)	<u>12.8</u> (.504)	<u>13.5</u> (.531)	<u>20.2</u> (.795)	-	<u>16.5</u> (.650)	<u>102</u> (4.016)

Device	A0		B0		D		D1		E		F	
	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	max.
C650, C850	<u>4.2</u> (.165)	<u>4.4</u> (.173)	<u>8.45</u> (.333)	<u>8.65</u> (.341)	<u>1.5</u> (.059)	<u>1.6</u> (.063)	<u>1.5</u> (.059)	-	<u>1.65</u> (.065)	<u>1.85</u> (.073)	<u>7.4</u> (.291)	<u>7.6</u> (.299)
During	K0			P P		0 P2		2	t		W	
Device	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.
C650, C850	<u>1.1</u> (.043)	<u>1.3</u> (.051)	<u>7.9</u> (.311)	<u>8.1</u> (.319)	<u>3.9</u> (.159)	<u>4.1</u> (.161)	<u>1.9</u> (.075)	<u>2.1</u> (.083)	<u>0.25</u> (.010)	0.35 (.014)	<u>15.7</u> (.618)	<u>16.3</u> (.642)

DIMENSIONS: MM (INCHES)

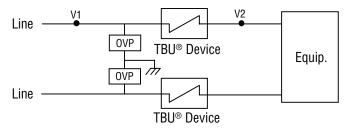
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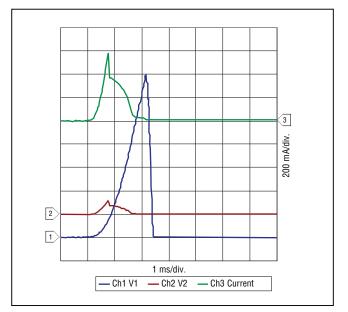
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Reference Application

The C-series devices are general use protectors used in a wide variety of applications. The following diagram is one common configuration example of C-series device placement. A cost-effective protection solution combines Bourns® TBU® protection devices with a pair of MOVs or Bourns® GDTs. The figure below demonstrates the operational characteristics of the circuit.



Common Configuration Diagram



C850 with G5200AS 4000 V Lightning 10/700 µsec, 150 A



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